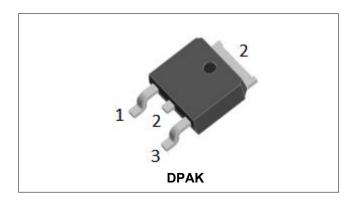






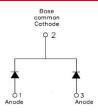
# 12CWQ06FN SCHOTTKY RECTIFIER



#### **Features**

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green products in compliance with the ROHS directive
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Applications**

- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	60	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> = 131°C, rectangular wave form	6(peg leg) 12(peg device)	Α
Peak One Cycle Non-Repetitive Surge Current(peg leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	126	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 6A, Pulse, T <sub>J</sub> = 25 °C	0.50	0.61	V
(per leg) *	$V_{F2}$	@ 6A, Pulse, T <sub>J</sub> = 125 °C	0.42	0.57	V
Reverse Current (per leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.07	3	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 125  ^{\circ}\text{C}$	3	35	mA
Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	340	360	pF

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%





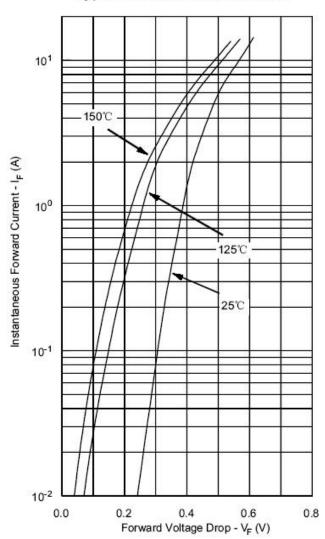


# **Thermal-Mechanical Specifications:**

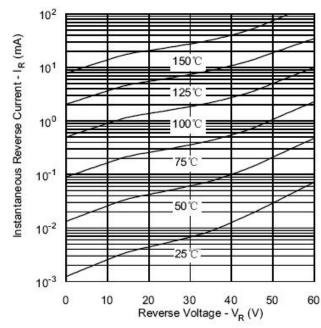
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to	Б		3.0(per leg)	00/14/
Case	R <sub>е</sub> ус	-	1.5(per device)	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			·

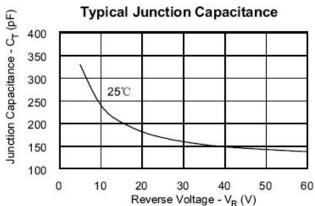
### **Ratings and Characteristics Curves**

#### **Typical Forward Characteristics**



### Typical Reverse Characteristics





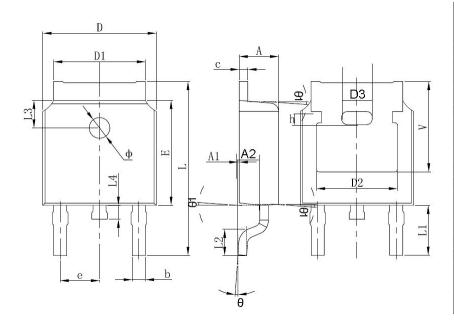
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### **Mechanical Dimensions DPAK**



SYMBOL	Millimeters		Inches		
STIMBUL	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.087	0.094	
A1	0.00	0.127	0.000	0.005	
b	0.66	0.86	0.026	0.034	
С	0.46	0.60	0.018	0.024	
D	6.50	6.70	0.256	0.264	
D1	5.13	5.46	0.202	0.215	
D2	4.83	REF.	0.190 REF.		
Е	6.00	6.20	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.70	10.40	0.381	0.409	
L1	2.90 REF.		0.144 REF.		
L2	1.40	1.70	0.055	0.067	
L3	1.60 REF.		0.063 REF.		
L4	0.60	1.00	0.024	0.039	
Ф	1.10	1.30	0.043	0.051	
Θ	0°	8°	0°	8°	
h	0.00	0.30	0.000	0.012	
V	5.35 REF.		0.211 REF.		

### **Ordering Information**

Device	Package	Shipping
12CWQ06FN	DPAK (Pb-Free)	2500pcs / reel
12CWQ06FNTR	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

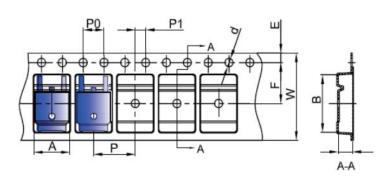
# **Marking Diagram**



Where XXXXX is YYWWL

**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Carrier Tape Specification DPAK**



SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
Α	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Ф1.45	Ф1.65	
E	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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